NSN 5961-01-199-7018

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-199-7018
Inclosure Material:
Glass
Overall Length:
0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.107 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
25.0 reverse voltage, dc
Current Rating Per Characteristic:
0.02 microamperes forward current, average peak
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Capacitance Rating In Picofarads:
0.2
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0